

-	215	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3	USPAT; US-PGPUB	2002/06/08 14:43
-	28	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3) and (inert or noble) adj gas	USPAT; US-PGPUB	2002/06/08 14:43
-	9	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3) and (inert or noble) adj gas) and barrier	USPAT; US-PGPUB	2002/06/08 14:44
-	0	("FOR0146").PN.	USPAT; US-PGPUB	2002/06/08 14:08
-	0	("FOR0146").PN.	JPO; DERWENT; IBM_TDB	2002/06/10 19:02
-	96	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3) and amorphous	USPAT; US-PGPUB	2002/06/08 14:43
-	16	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3) and amorphous) and (inert or noble) adj gas	USPAT; US-PGPUB	2002/06/08 14:43
-	6	((438/166) or (438/486) or (438/476)).CCLS.) and getter\$3) and amorphous) and (inert or noble) adj gas) and barrier	USPAT; US-PGPUB	2002/06/08 14:44
-	1	("6396147").PN.	USPAT; US-PGPUB	2002/06/10 17:37
-	1	("5789284").PN.	USPAT; US-PGPUB	2002/06/10 17:37
-	0	("FOR 146").PN.	JPO; DERWENT; IBM_TDB	2002/06/10 19:04
-	9	(metallic or(metal\$4 adj (cluster\$1 or element\$1))) with (anneal\$ with (electric adj current))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/21 16:53
-	1	("20020086469").PN.	USPAT; US-PGPUB	2003/06/02 17:02
-	19346	kim.in.	USPAT; US-PGPUB	2003/06/02 17:02
-	8679	getter\$3	USPAT; US-PGPUB	2003/06/02 17:03
-	44	kim.in. and getter\$3	USPAT; US-PGPUB	2003/06/02 17:03
-	16337	getter\$3 or getter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/06/03 13:50
-	2089	"semiconductor energy laboratory"	USPAT; US-PGPUB	2003/06/03 13:52
-	19706	tft or (thin adj film adj transistor)	USPAT; US-PGPUB	2003/06/03 13:58
-	641	(getter\$3 or getter) and (tft or (thin adj film adj transistor))	USPAT; US-PGPUB	2003/06/03 14:00
-	248	((getter\$3 or getter) and (tft or (thin adj film adj transistor))) not "semiconductor energy laboratory"	USPAT; US-PGPUB	2003/06/03 14:00
-	40	((getter\$3 or getter) and (tft or (thin adj film adj transistor))) not "semiconductor energy laboratory") and @ad<20010216) and 438/\$.ccls.	USPAT; US-PGPUB	2003/06/03 14:02
-	111	((getter\$3 or getter) and (tft or (thin adj film adj transistor))) not "semiconductor energy laboratory") and @ad<20010216	USPAT; US-PGPUB	2003/06/03 18:03